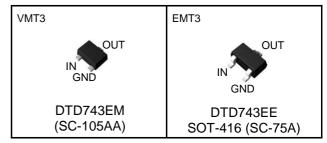


# DTD743E series

# NPN 200mA 30V Digital Transistors (Bias Resistor Built-in Transistors)

Parameter	Value
V <sub>CC</sub>	30V
I <sub>C(MAX.)</sub>	200mA
R <sub>1</sub>	4.7kΩ
$R_2$	4.7kΩ

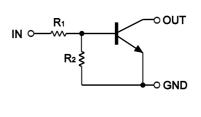
#### Outline

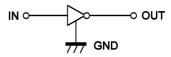


#### Features

- 1) Built-In Biasing Resistors,  $R_1 = R_2 = 4.7k\Omega$ .
- 2) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see inner circuit).
- 3) The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of completely eliminating parasitic effects.
- 4) Only the on/off conditions need to be set for operation, making the circuit design easy.
- 5) Complementary PNP Types :DTB743E series
- 6) Lead Free/RoHS Compliant.

#### •Inner circuit





#### Application

Switching circuit, Inverter circuit, Interface circuit, Driver circuit

#### Packaging specifications

Part No.	Package	Package size (mm)	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit (pcs)	Marking
DTD743EM	VMT3	1212	T2L	180	8	8,000	M23
DTD743EE	EMT3	1616	TL	180	8	3,000	M23

# ● Absolute maximum ratings (Ta = 25°C)

Parameter	Symbol	Values	Unit
Supply voltage	V <sub>CC</sub>	30	V
Input voltage	V <sub>IN</sub>	-10 to +20	V
Collector current	I <sub>C(MAX.)</sub> *1	200	mA
Power dissipation	P <sub>D</sub> *2	150	mW
Junction temperature	T <sub>j</sub>	150	°C
Range of storage temperature	T <sub>stg</sub>	-55 to +150	°C

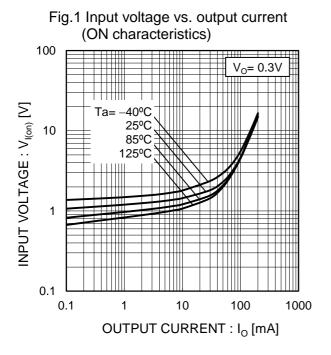
# ●Electrical characteristics(Ta = 25°C)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Input voltage	$V_{I(off)}$	$V_{CC} = 5V, I_{O} = 100 \mu A$	-	-	0.5	V	
	$V_{I(on)}$	$V_0 = 0.3V, I_0 = 20mA$	2.5	-	-	V	
Output voltage	$V_{O(on)}$	I <sub>O</sub> / I <sub>I</sub> = 50mA / 2.5mA	-	0.07	0.3	V	
Input current	I <sub>I</sub>	V <sub>I</sub> = 5V	-	-	1.4	mA	
Output current	I <sub>O(off)</sub>	$V_{CC} = 30V, V_I = 0V$	-	-	0.5	μΑ	
DC current gain	Gı	$V_O = 2V, I_O = 100 \text{mA}$	115	-	-	-	
Input resistance	R <sub>1</sub>	-	3.29	4.7	6.11	kΩ	
Resistance ratio	R <sub>2</sub> /R <sub>1</sub>	-	0.8	1	1.2	-	
Transition frequency	f <sub>T</sub> *1	$V_{CE} = 10V, I_{E} = -5mA,$ f = 100MHz	ı	260	ı	MHz	

<sup>\*1</sup> Characteristics of built-in transistor

<sup>\*2</sup> Each terminal mounted on a reference footprint

#### ●Electrical characteristic curves(Ta = 25°C)



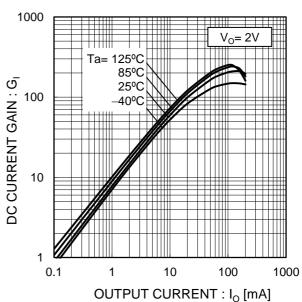
(OFF characteristics) 100  $V_{CC} = 5V$ OUTPUT CURRENT : I<sub>o</sub> [mA] 10 Ta= 125°C 85°C 25°C -40°C 0.1 2 0 INPUT VOLTAGE :  $V_{I(off)}[V]$ 

Fig.2 Output current vs. input voltage

Fig.3 Output current vs. output voltage  $I_1=1.0mA$ 

0.9mA 200 0.8mA OUTPUT CURRENT : Io [mA] 0.7mA 150 0.6mA 0.5mA 100 0.4mA 0.3mA 50 Ta=25°C 0.2mA 0А 0 0 10 OUTPUT VOLTAGE : Vo [V]

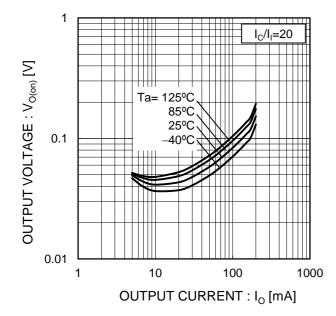
Fig.4 DC current gain vs. output current



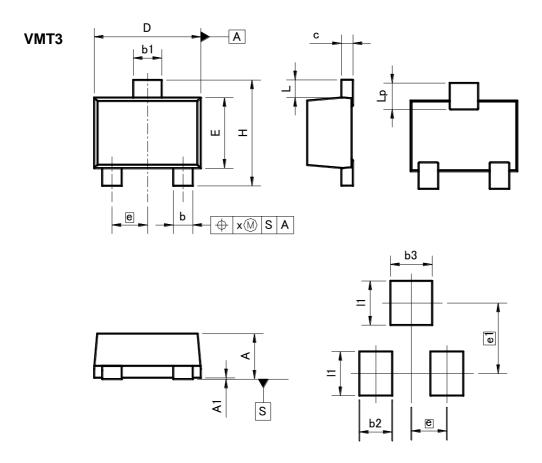
www.rohm.com

## ●Electrical characteristic curves(Ta = 25°C)

Fig.5 Output voltage vs. output current



## ●Dimensions (Unit:mm)



### Patterm of terminal position areas

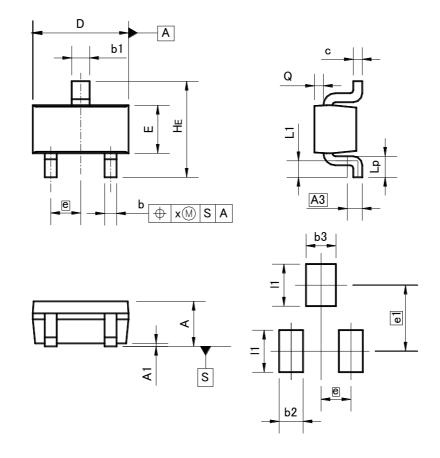
DIM	MILIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	0.45	0.55	0.018	0.022	
A1	0.00	0.10	0	0.004	
b	0.17	0.27	0.007	0.011	
b1	0.27	0.37	0.011	0.015	
С	0.08	0.18	0.003	0.007	
D	1.10	1.30	0.043	0.051	
Е	0.70	0.90	0.028	0.035	
е	0.4	40	0.0	02	
HE	1.10	1.30	0.043	0.051	
L	0.10	0.30	0.004		
Lp	0.20	0.40	0.008	-	
х	_	0.10		0.004	

DIM	MILIMETERS		INCHES		
DIIVI	MIN	MAX	MIN	MAX	
e1	0.8	80 0.03		03	
b2	_	0.37	ı	0.015	
b3	-	0.47	ı	0.019	
l1	_	0.50	ı	0.02	

Dimension in mm/inches

## ●Dimensions (Unit:mm)





#### Patterm of terminal position areas

DIM	MILIMI	MILIMETERS		HES
DIM	MIN	MAX	MIN	MAX
Α	0.60	0.80	0.024	0.031
A1	0.00	0.10	0	0.004
A3	0.2	25	0.01	
b	0.15	0.30	0.006	0.012
b1	0.25	0.40	0.01	0.016
С	0.10	0.20	0.004	0.008
D	1.50	1.70	0.059	0.067
E	0.70	0.90	0.028	0.035
е	0.50		0.0	02
HE	1.40	1.80	0.055	0.071
L1	0.10	ı	0.004	-
Lp	0.15		0.006	_
Q	0.05	0.25	0.002	0.01
Х	_	0.10	_	0.004

DIM	MILIMETERS		INCHES		
MIN		MAX	MIN	MAX	
e1	1.	10	0.04		
b2	ı	0.40	ı	0.016	
b3	ı	0.50	ı	0.02	
11	-	0.70	-	0.028	

Dimension in mm/inches

#### Notes

No copying or reproduction of this document, in part or in whole, is permitted without the consent of ROHM Co.,Ltd.

The content specified herein is subject to change for improvement without notice.

The content specified herein is for the purpose of introducing ROHM's products (hereinafter "Products"). If you wish to use any such Product, please be sure to refer to the specifications, which can be obtained from ROHM upon request.

Examples of application circuits, circuit constants and any other information contained herein illustrate the standard usage and operations of the Products. The peripheral conditions must be taken into account when designing circuits for mass production.

Great care was taken in ensuring the accuracy of the information specified in this document. However, should you incur any damage arising from any inaccuracy or misprint of such information, ROHM shall bear no responsibility for such damage.

The technical information specified herein is intended only to show the typical functions of and examples of application circuits for the Products. ROHM does not grant you, explicitly or implicitly, any license to use or exercise intellectual property or other rights held by ROHM and other parties. ROHM shall bear no responsibility whatsoever for any dispute arising from the use of such technical information.

The Products specified in this document are intended to be used with general-use electronic equipment or devices (such as audio visual equipment, office-automation equipment, communication devices, electronic appliances and amusement devices).

The Products specified in this document are not designed to be radiation tolerant.

While ROHM always makes efforts to enhance the quality and reliability of its Products, a Product may fail or malfunction for a variety of reasons.

Please be sure to implement in your equipment using the Products safety measures to guard against the possibility of physical injury, fire or any other damage caused in the event of the failure of any Product, such as derating, redundancy, fire control and fail-safe designs. ROHM shall bear no responsibility whatsoever for your use of any Product outside of the prescribed scope or not in accordance with the instruction manual.

The Products are not designed or manufactured to be used with any equipment, device or system which requires an extremely high level of reliability the failure or malfunction of which may result in a direct threat to human life or create a risk of human injury (such as a medical instrument, transportation equipment, aerospace machinery, nuclear-reactor controller, fuel-controller or other safety device). ROHM shall bear no responsibility in any way for use of any of the Products for the above special purposes. If a Product is intended to be used for any such special purpose, please contact a ROHM sales representative before purchasing.

If you intend to export or ship overseas any Product or technology specified herein that may be controlled under the Foreign Exchange and the Foreign Trade Law, you will be required to obtain a license or permit under the Law.



Thank you for your accessing to ROHM product informations. More detail product informations and catalogs are available, please contact us.

# ROHM Customer Support System

http://www.rohm.com/contact/

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Bipolar Transistors - Pre-Biased category:

Click to view products by ROHM manufacturer:

Other Similar products are found below:

RN1607(TE85L,F) DTA124GKAT146 DTA144WETL DTA144WKAT146 DTC113EET1G DTC115TKAT146 DTC144ECA-TP

DTC144VUAT106 MUN5241T1G BCR158WH6327XTSA1 NSBA114TDP6T5G NSBA143ZF3T5G NSBC114YF3T5G NSBC123TF3T5G

SMUN5235T1G SMUN5330DW1T1G SSVMUN5312DW1T2G RN1303(TE85L,F) RN4605(TE85L,F) TTEPROTOTYPE79

DDTC114EUAQ-7-F EMH15T2R SMUN2214T3G NSBC114TF3T5G NSBC143ZPDP6T5G NSVMUN5113DW1T3G

SMUN5230DW1T1G SMUN5133T1G SMUN2214T1G DTC114EUA-TP NSBA144EF3T5G NSVDTA114EET1G 2SC2223-T1B-A

2SC3912-TB-E SMUN5237DW1T1G SMUN5213DW1T1G SMUN5114DW1T1G SMUN2111T1G NSVDTC144EM3T5G DTC124ECA-TP DTC123TM3T5G DTA114ECA-TP DTA113EM3T5G DCX115EK-7-F DTC113EM3T5G NSVMUN5135DW1T1G

NSVMUN2237T1G NSVDTC143ZM3T5G SMUN5335DW1T2G SMUN5216DW1T1G